



OKI Semiconductor

FEDL6585-03

Issue Date: Aug. 25, 2004

MSM6585

ADPCM Voice Synthesis IC

GENERAL DESCRIPTION

The MSM6585 is an version-up product of the MSM5205 voice synthesis IC. Mainly improved points are improvement for the precision of an internal DA converter, a built-in low-pass filter, and expansion on the sampling frequency. The MSM6585 does not include a control circuit to drive an external memory similar to the MSM5205. Therefore, the MSM6585 can be connected with not only semiconductor memories, but other memory media (CD-ROM, etc.) by the control of CPU.

FEATURES

- 4-bit ADPCM method
- Built-in 12-bit DA converter
- Built-in low-pass filter (LPF) (-40dB/oct)
- Sampling frequencies: 4k/8k/16k/32kHz
- Master clock frequency (ceramic oscillator): 640kHz
- Voice data synthesis: Supported by voice analysis editing tool AR207
- Package options:

18-pin plastic DIP (DIP18-P-300-2.54) (MSM6585RS)

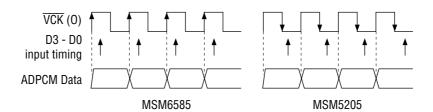
24-pin plastic SOP (SOP24-P-430-1.27-K) (MSM6585MAZXXX)

30-pin plastic SSOP (SSOP30-P-56-0.65-K) (MSM6585MBZXXX)

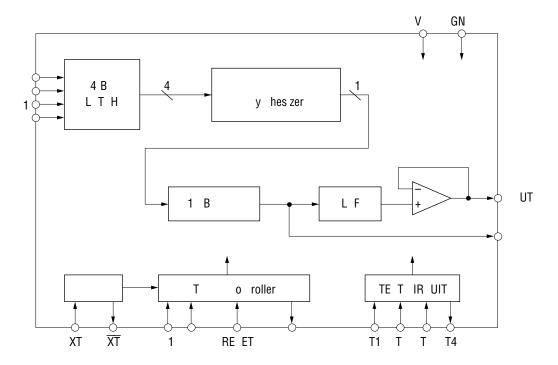
DIFFERENCES BETWEEN MSM6585 AND MSM5205

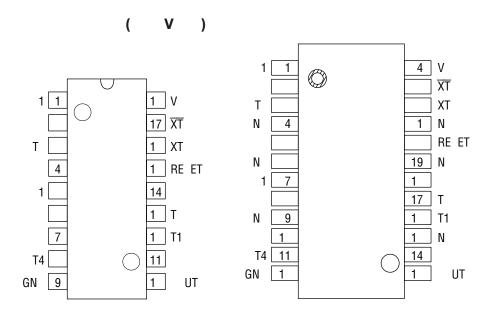
MSM6585 MSM5205 • Master clock frequency: 640kHz 384kHz • Sampling frequency: 4k/8k/16k/32kHz 4k/6k/8kHz• ADPCM bit length: 4-bit 3-bit/4-bit • DA Converter: 12-bit 10-bit • Low-pass filter: Included (-40dB/oct) Not included • Overflow preventing circuit: Included Not included • Power supply voltage: 4.5 to 5.5V 3.0 to 6.0V • Operating current consumption: 10mA 4mA • Operating temperature: -40 to +85°C $-30 \text{ to } +70^{\circ}\text{C}$

• D3 to D0 input timing

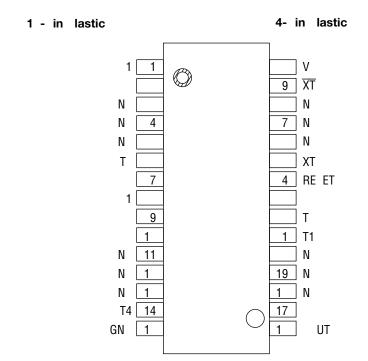


Κ





N : No co ec o



N : No co ec o

3 - in lastic

	in		ymbol ype		escription		
1	1	1	1		s o de er e he s I freq e cy. The s I freq e c es of k, 1 k, k, d 4kHz c be selec ed by		
				'	co b o s. ee he s I freq e c es FUN TI N L E RI TI N o he selec o of co b o s.		
			T	I	o es he er lcrc . e hs o h h level or ke o e bec se hs b l ll ressor.		
4 7	, 7, , 1	7 1		I	l s for d. o es he er l c rc. ke h s o e.		
	11	14	T4		oeshe er lcrc. kehs oe.		
_ 9	1	1	GN	_	Gro d		
1	1	1	UT		00 he lo voce fro he low ssfler. 0 ec . 1 μF c c or 0 h s . ee he UT co ec c rc FUN TI N L E RI TI N o he co ec c rc .		
11	14	17			o o he lo vo ce fro he co ver er.		
1	1	1	T1		s o es he er l c rc . e hese s o low level or ke he		
1	17		T	'	o e bec se II dow res s ors re cl ded.		
14	1				Th s o she s I freq e cy selec ed by he co b o s of 1 d . The voce sy hesssrsorsos by sy chroz wh.		
1		4	RE ET	I	Rese . The vo ce sy hes s c rc s I zed by sy chro z w h . If h s s se o h h level, he o d s re d s bled by sy chro z w h . The UT d s o 1/V d beco e he s e of o vo ce.		
1			XT	I	o co $$ ec $$ osc II $$ or. Whe $$ he ex er $$ I clock s $$ sed, fro $$ h s $$.		
17		9	ΧT		o co ec osc II or. Whe he ex er I clock s sed, ke h s o e .		
1	4		V	_	owers ly . I ser by ss c c or of .1 μF or ore be wee h s d he GN .		

X

GN = V

arameter	ymbol	ondition	ating	nit
ower ly Vol e	V	T = °	o +7.	V
I Vol e	V _{IN}	T = °	oV + .	V
or e Te er re	T TG	_	- 0+1	0

GN = V

arameter	ymbol	ondition	ange	nit
ower ly Vol e	V	_	4. 0 .	V
er Te er re	To	_	-4 0+	0
s er lock Freq e cy	f	oscII or co ec o	4	kHz

Н

haracteristics

V = 4. 0 . V, GN = V, T = -4 0 + $^{\circ}$

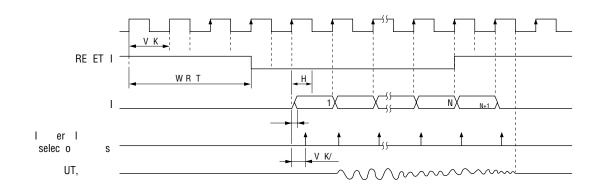
arameter	ymbol	ondition	in.	yp.	ax.	nit
"H" I Vol e	V _{IH}	_	. ×V	_	V + .1	V
"L" I Vol e	V _{IL}	_	1	_	. ×V	V
"H" Vol e	V _H	V K: I H = -4 μ	V4	_	_	٧
"L" Vol e	V L	V K: I L = 4 μ	_	_	.4	V
"H" I rre	I _{IH1}	T1, T , RE ET: V _{IH} = V		1	4	μ
"H" I rre	I _{IH}	1, , , T : V _{IH} = V	_	_	1	μ
"H" I rre	I _{IH}	XT: V _{IH} = V	_	_		μ
"L" I rre	I _{IL1}	$T:V_{IL} = V$	-4	-1	-	μ
"L" I rre	I _{IL}	1, , , T1, T , RE ET: V _{IL} = V	-1	_	_	μ
"L" I rre	I _{IL}	XT=V _{IL} = V	_	_	_	μ
rre os o	I	f _{OSC} = 4 kHz, No lo d	_		1	
Rel ve Error	IV EI	No lo d	_	_	4	V
I ed ce	R	_	1	_	4	kΩ
L F Lo d Res s ce	R _{UT}	<u> </u>		_	_	kΩ

haracteristics

arameter	ymbol	ondition	in.	yp.	ax.	nit
r I sc II o y ycle	f _{d y}	_	4			%
RE ET I lse W d h	WRT	$f = 4kHz \cdots V K = \mu S$	×v K	_	_	μS
e T e		= kHz ··· = 1 μs =1 kHz ··· = . μs	_			μS
Hold T e	Н	= kHz ··· = 1. μs	v κ/	_	_	μS

W

E E E WEE

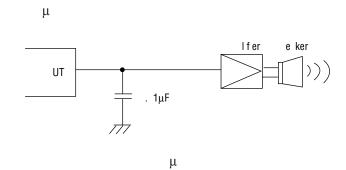


 $\overline{\text{VCK}}$

E E E WEE

E

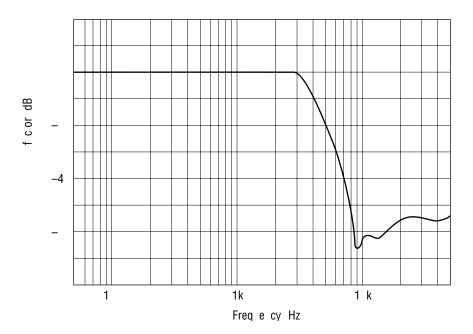
1		ampling frequency (f)	utoff frequency (f)
L	L	4 kHz	1. kHz
Н	L	kHz	. kHz
L	Н	1 kHz	.4 kHz
Н	Н	kHz	1 . kHz



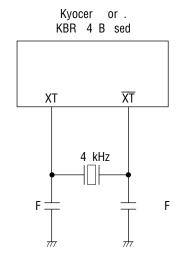
W 9 9 ×

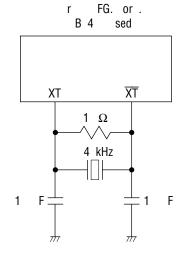
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Ω

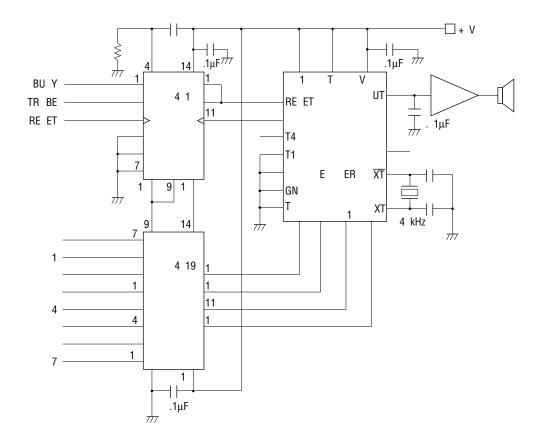


K G

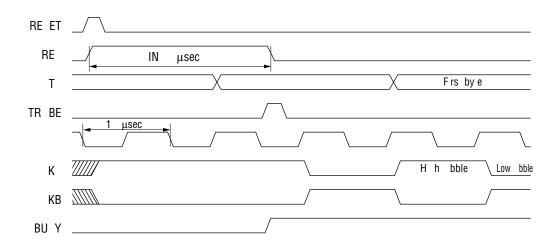




entronics nterface ircuit (sampling frequency: kHz)

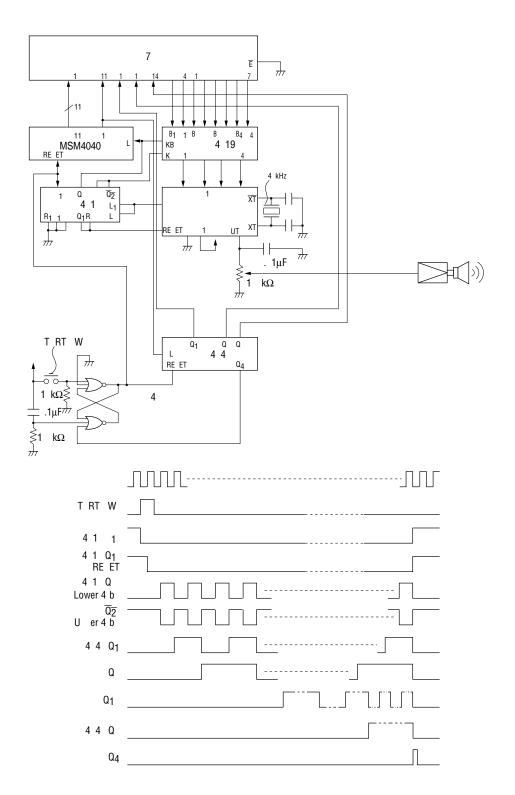


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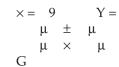


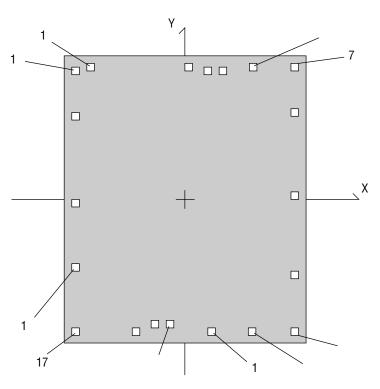
xample of nterface ircuit with K-bit

K E



ad ayout



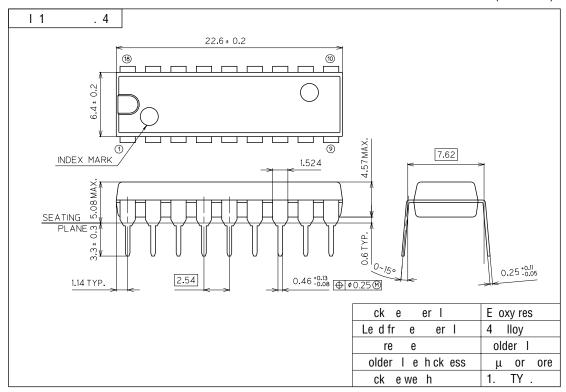


ad oordiantes

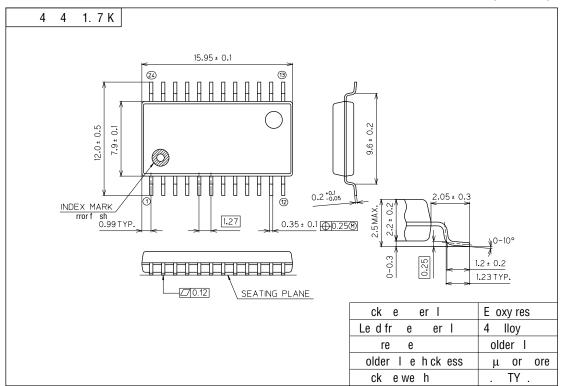
o. ame X-axis Y-axis o. ame X-axis Y-axis 1 1 77 -1 11 UT 1 1 19 -1 1 -11 1 1 1 -1 1 1 1 4 1 -1 -1 1 9 1 1 44 1 -1 -1 -1 -1 1 1 1 1 1 1 1 -1								υ : μ
19 -1 1 -11 1 T 1 -1 1 T1 -1 1 79 4 1 -94 14 T -1 1 9 1 1 44 1 -1 -1 - 1 1 9 1 1 1 1 1 -1	0.	ame	X-axis	Y-axis	0.	ame	X-axis	Y-axis
T 1 -1 1 T1 -1 1 79 4 1 -94 14 T -1 1 9 1 1 44 1	1	1	77	-1	11	UT		1
4 1 -94 14 T -1 1 9 1 1 44 1 -1 -1 -1 1 1 1 9 1			19	-1	1		-11	1
1 1 44 1 -1 - 1 1 9 1 RE ET -1 -1 7 1 1 17 XT -1 1 -1 1 1 1 1 XT -9 -1 9 V 447 1 19 V -99 -1 49		T	1	-1	1	T1	-1	1 79
1 1 9 1 RE ET -1 - 1 7 1 1 17 XT -1 1 -1 T4 1 1 XT - 9 -1 9 V 447 1 19 V - 99 -1 49	4		1	-94	14	T	-1	1 9
7 1 1 1 17 XT -1 1 -1 T4 1 1 1 XT -9 -1 9 V 447 1 19 V -99 -1 49		1	1	44	1		-1	_
T4 1 1 XT - 9 -1 9 V 447 1 19 V - 99 -1 49			1	1 9	1	RE ET	-1	- 1
9 V 447 1 19 V - 99 -1 49	7		1	1	17	XT	-1 1	-1
		T4		1	1	XT	- 9	-1
1 V 7 1 V -119 -1 49	9	V	447	1	19	V	- 99	-1 49
	1	V	7	1		V	-119	-1 49

Κ

(Unit: mm)

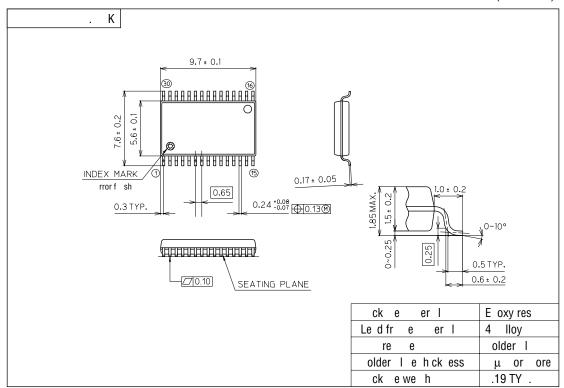


(Unit: mm)



Q Q Q JQJ G

(Unit: mm)



Q Q JQJ Q G

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REVISION HISTORY

Document		Page		
No.	Date	Previous Edition	Current Edition	Description
E2D0011-39-91 Sep. 1999			1	Final edition 1
FEDL6585-02	Jun. 30, 2004		_	Final edition 2
		1	1	Changed the voice analysis editing tools from AR203 and AR204 to AR207.
		1	1	Changed the package product names from MSM6585GS-K and MSM6585GS-AK to MSM6585MAZXXX and MSM6585MBZXXX, respectively.
FEDL6585-03	Aug. 25, 2004	10	10	Changed the product name of the circuit block in the upper-left portion of the block diagram from MSM4013 to MSM4040.

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